MDC5100

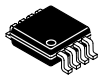
Advance Information

Antenna Switch Controller

ANTENNA SWITCH CONTROLLER

The MDC5100 is designed to control GaAs RF switches which require positive and negative going control voltages to select the switch path. All input control signals are 3 V CMOS–logic compatible to allow for direct interface to a microcontroller. The device also has an accessory detect pin for use in applications where there is a portable handset to mobile adapter. The device is designed to interface directly with Double Pull–Double Throw (DPDT) switches such as the M/A–Com SW 363.

This device in combination with a GaAs RF switch can be used to achieve duplex isolation in many Time Division Duplex Radios like DECT or in Frequency Division Duplex Radios employing time division multiple access with staggered Transit/Receive time slots such as GSM. It can also be used to control an RF switch in dual band radio applications. The device is housed in a miniature Micro–8 for minimum space utilization.



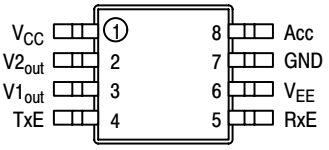
PLASTIC PACKAGE
CASE 846A–02
(Micro–8)

Features

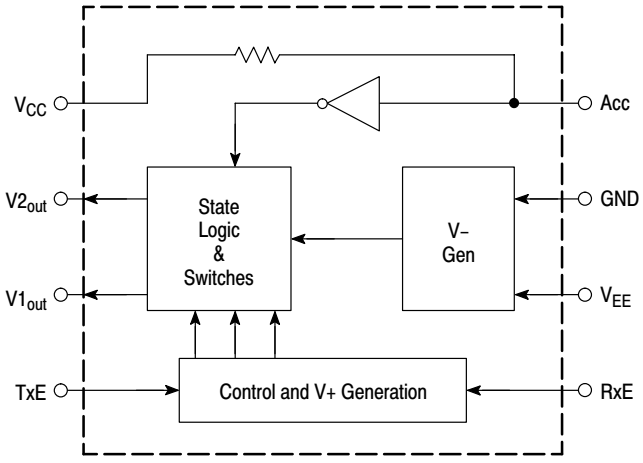
- Micro–miniature Low Profile Micro 8 Package
- 3 V CMOS Logic Control Inputs
- Ultra–low Quiescent Current of 400 μA Typical
- Wide Operating Temperature Range of –40 to 85°C

Applications

- GSM and PCS Portable Phones
- Mobile to Portable Accessories
- Wireless LAN Modems
- Specialized TDD and TDMA Radios
- Dual Band Phones



(Top View)



Functional Block Diagram

This document contains information on a new product. Specifications and information herein are subject to change without notice.

August, 2001 – Rev. 1
Publication Order Number:
MDC5100/D

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Positive Supply Voltage	V_{CC}	6	V
Negative Supply Voltage	$\|V_{EE}\|$	12	V
Differential Supply Voltage	$V_{CC}–V_{EE}$	15	V
Voltage Range at Any Input Pin (TxE, RxE, Acc)	V_{in}	–1 to V_{CC}	V
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{stg}	–65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Total Power Dissipation Derate above 25°C	P_D	510 4	mW mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	245	°C/W

DEVICE MARKING

5100

ORDERING INFORMATION

MDC5100R2	13 inch Reel, 4000 units

TRUTH TABLE

Input Logic			Output Logic		
RxE	TxE	ACC	$V1_{out}$	$V2_{out}$	
0	0	0	GND	GND	
0	0	1	GND	GND	
0	1	0	V–	V+	
0	1	1	V+	V–	
1	0	0	V+	V–	
1	0	1	V–	V+	
1	1	0	V+	V+	Invalid state, should be
1	1	1	V+	V+	prohibited in control logic/software

Note 1: ACC “0” = Open, ACC “1” = 10 kΩ to GND
Note 2: V+ is nominally V_{IH} – 0.1
Note 3: V– is nominally V_{EE} – 1 V

PIN DESCRIPTION

Pin	Name	Functional Description
1	V_{CC}	Positive Supply
2	$V2_{out}$	Antenna Control Output 1, V+ is referenced to the V_{IH} of TxE, RxE and V– is referenced to the V_{EE} Voltage
3	$V1_{out}$	Antenna Control Output 2, V+ is referenced to the V_{IH} of TxE, RxE and V– is referenced to the V_{EE} Voltage
4	TxE	Transmit Enable Input
5	RxE	Receive Enable Input
6	V_{EE}	Negative Supply
7	GND	Ground
8	Acc	Accessory Present Input

ELECTRICAL CHARACTERISTICS (V_{CC} = 2.75 V, V_{EE} = –10 V, T_A = 25°C)

Characteristic	Symbol	Min	Typ	Max	Unit
RECOMMENDED OPERATING CONDITIONS					
Positive Supply Voltage	V_{CC}	1.8		5.0	V
Negative Supply Voltage	V_{EE}	–10		–5.0	V
Voltage Range at Any Input Pin (TxE, RxE, Acc)	V_{in}	0		V_{CC}	V
Ambient Operating Temperature Range	T_A	–40		85	°C
DC ELECTRICAL CHARACTERISTICS					
Positive Supply Current (Acc connected to GND) Negative Supply Current (Acc, V1, V2 unterminated)	I_{CC} I_{EE}	100	400	500 –200	μA
RxE or TxE Input High State for V1 or V2 = V+ RxE or TxE Input Low State for V1 or V2 = V–	V_{IH} V_{IL}	2.65		 0.4	V
V1, V2 Output High State – TxE or RxE = V_{IH}, I_{OH} = –25 μA (1) V1, V2 Output Low State – TxE or RxE = V_{IL}, I_{OL} = 25 μA (1)	V+ V–	2.50		 –5.75	V
Accessory Resistance for V1 = V–, V2 = V+ (TxE = V_{IH}, RxE = V_{IL}) Accessory Resistance for V1 = V+, V2 = V– (TxE = V_{IH}, RxE = V_{IL})	Racc Racc	800		 12	kΩ
AC ELECTRICAL CHARACTERISTICS					
Propagation Delay – RxE/TxE to V1/V2 (Racc = 800 kΩ to GND)	T_{PLH} (2) T_{PHL} (2)	0.016 0.004		0.5 1.4	μsec μsec
Propagation Delay – RxE/TxE to V1/V2 (Racc = 12 kΩ to GND)	T_{PLH} T_{PHL}	0.35 0.005		4.0 1.4	μsec μsec
Propagation Delay – Acc to V1/V2 through 12 kΩ	T_{PLH} T_{PHL}	0.4 0.1		7.5 5.0	μsec μsec
Transition Time of V1/V2 from RxE or TxE (Racc = 800 k to GND)	T_{rise} (3) T_{fall} (3)	0.3 0.3		7.4 4.4	μsec μsec
Transition Time of V1/V2 from RxE or TxE (Racc = 12 k to GND)	T_{rise} T_{fall}	0.3 0.2		16 4.0	μsec μsec
Transition Time of V1/V2 from Acc Input	T_{rise} T_{fall}	0.3 0.3		4.1 4.1	μsec μsec

NOTES: 1 Refer to truth table for input test states
2. T_{PLH} and T_{PHL} are measured from the 50% point of input waveform to 50% of the output waveform
3. T_{rise} and T_{fall} are measured from the 10% point to the 90% point of the output

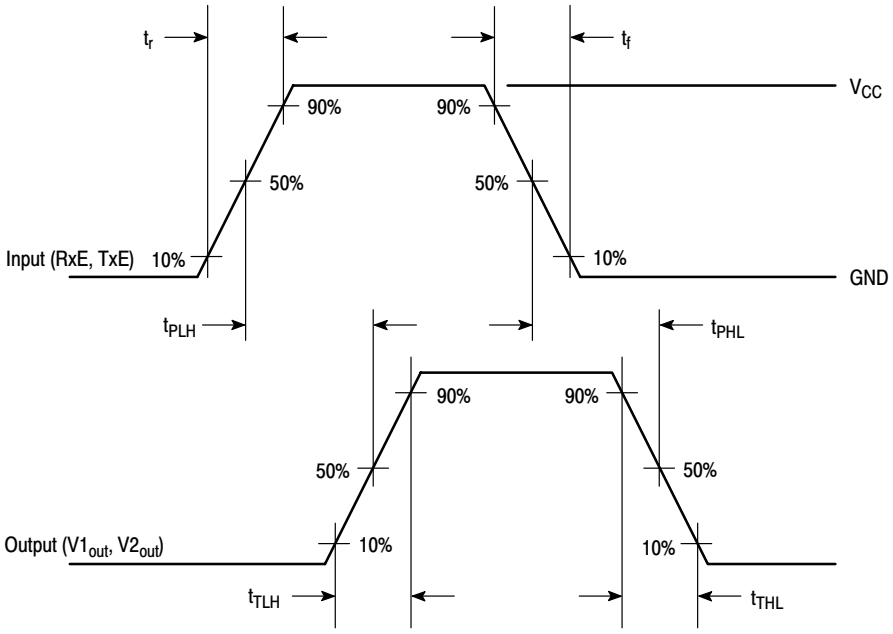


Figure 1.

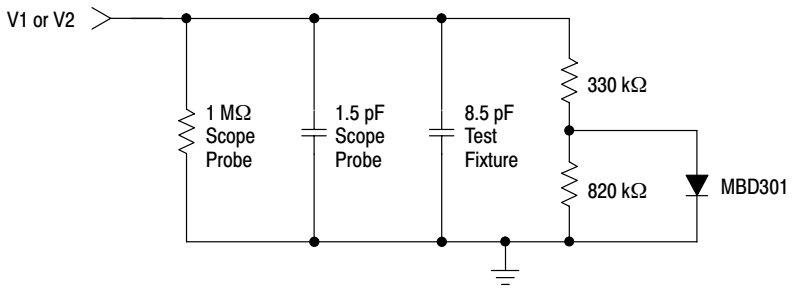


Figure 2. AC Test Load

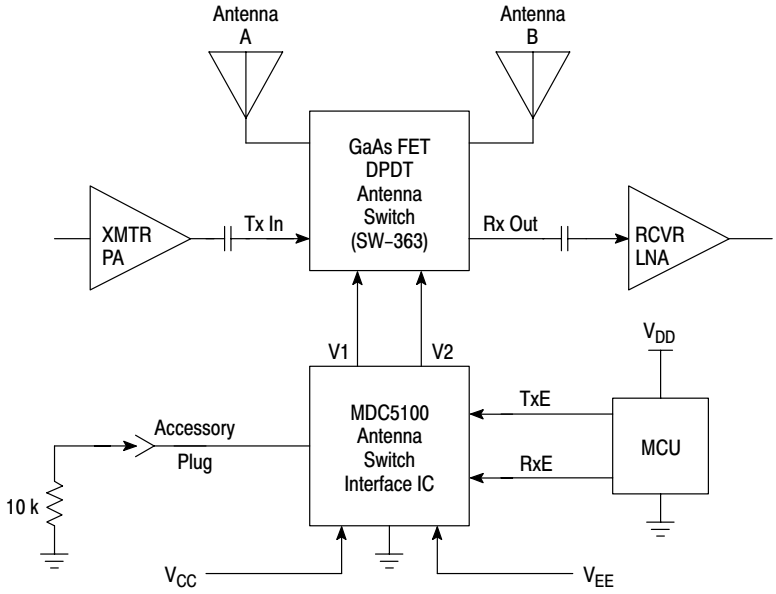


Figure 3. Diversity Antenna Application

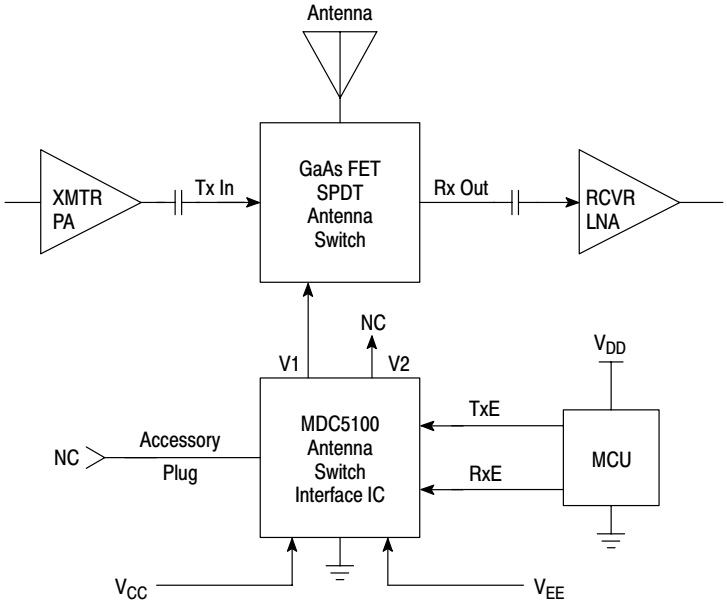
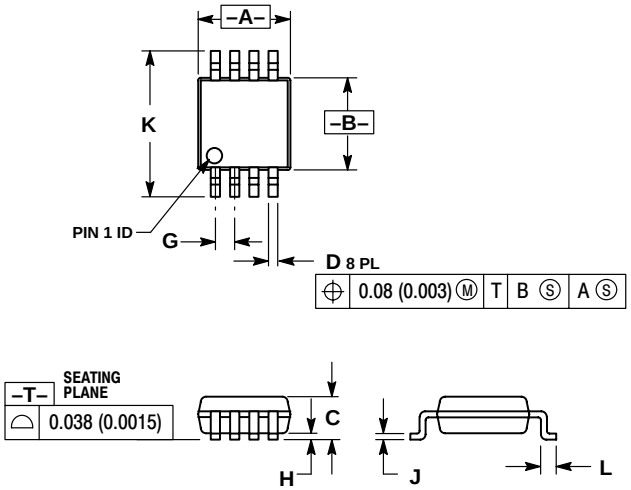


Figure 4. T_{DD} or Half−Duplex Handie−Talkie Application

PACKAGE DIMENSIONS

Micro8
CASE 846A–02
ISSUE E



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	---	1.10	---	0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
H	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

Notes

PUBLICATION ORDERING INFORMATION

Literature Fulfillment:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada
Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada
Email: ONlit@hibbertco.com

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center
4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031
Phone: 81–3–5740–2700
Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local
Sales Representative.

MDC5100/D